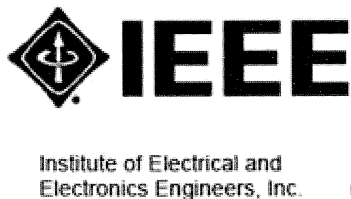
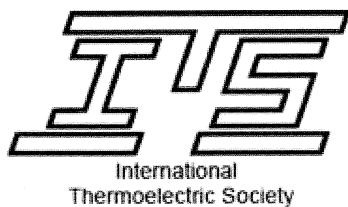


# **Proceedings ICT '07**

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# International Conference on Thermoelectrics 2007

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